

PC815 Series

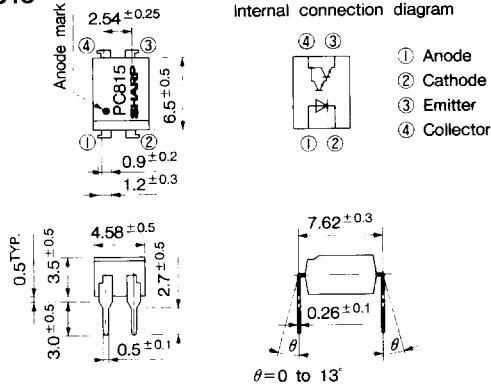
* Lead forming type (I type) and taping reel type (P type) are also available. (PC815i/PC815P) (Page 656)
** TÜV(VDE0884) approved type is also available as an option.

■ Features

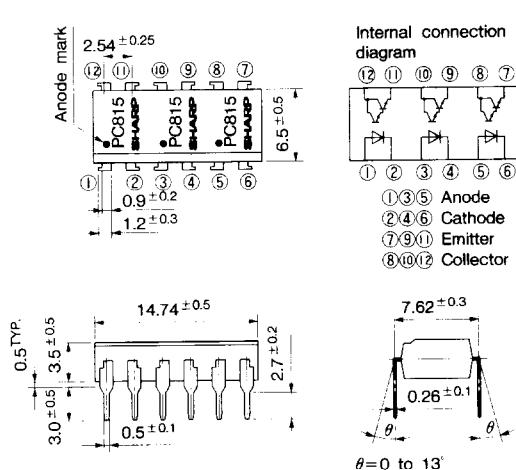
1. High current transfer ratio
(CTR: MIN. 600% at $I_F = 1\text{mA}$, $V_{CE} = 2\text{V}$)
2. High isolation voltage between input and output
($V_{iso} : 5\,000\text{V}_{rms}$)
3. Compact dual-in-line package
PC815 : 1-channel type PC825 : 2-channel type
PC835 : 3-channel type PC845 : 4-channel type
4. Recognized by UL file No. E64380

■ Outline Dimensions

PC815



PC835

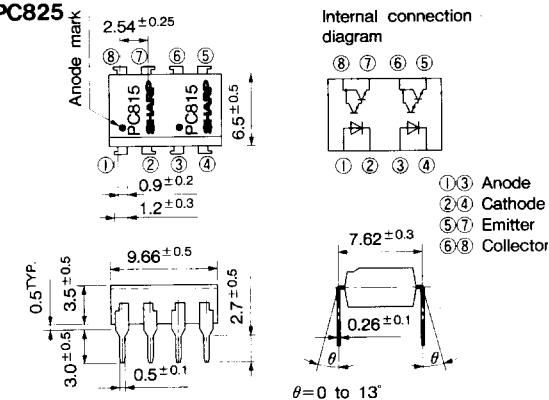


High Sensitivity, High Density Mounting Type Photocoupler

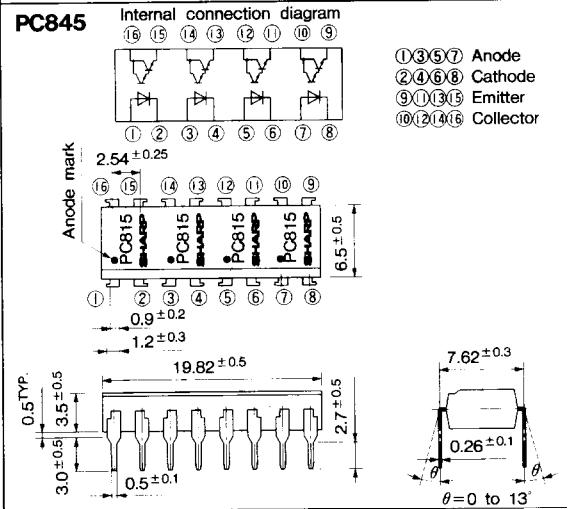
■ Applications

1. System appliances, measuring instruments
2. Industrial robots
3. Copiers, automatic vending machines
4. Signal transmission between circuits of different potentials and impedances

PC825



PC845



Absolute Maximum Ratings

(Ta = 25°C)

Parameter	Symbol	Rating	Unit
Input	Forward current	I _F	50 mA
	* ¹ Peak forward current	I _{FM}	1 A
	Reverse voltage	V _R	6 V
Output	Power dissipation	P	70 mW
	Collector -emitter voltage	V _{CEO}	35 V
	Emitter collector voltage	V _{ECD}	6 V
	Collector current	I _C	80 mA
Collector power dissipation		P _C	150 mW
Total power dissipation		P _{tot}	200 mW
* ² Isolation voltage		V _{iso}	5000 V _{rms}
Operating temperature		T _{opr}	-30 to +100 °C
Storage temperature		T _{stg}	-55 to +125 °C
'(Soldering temperature		T _{sol}	260 °C

*1 Pulse width= 100 μs, Duty ratio – 0.001

*2 40 to 60 %RH, AC for 1 minute

*3 For 10 seconds

Electro-optical Characteristics

(Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Input	Forward voltage	V _F I _F =20mA		1.2	1.4	V	
	Peak forward voltage	V _{FM} I _{FM} =0.5A		—	3.0	V	
	Reverse current	I _R V _R =4V	—	—	10	μA	
Output	Terminal capacitance	C _t V=0, f=1kHz		30	250	pF	
Collector dark current	I _{CEO}	V _{CE} =10V, I _F =0		—	10 ⁶	A	
Current transfer ratio	CTR	I _F =1mA, V _{CE} =2V	600	1600	7500	%	
Collector-emitter saturation voltage	V _{(CE)sat}	I _F =20mA, I _c =5mA	—	0.8	1.0	V	
Isolation resistance	R _{ISO}	DC500V, 40 to 60%RH	5 × 10 ¹⁰	10 ¹¹	—	Ω	
Floating capacitance	C _f	V=0, f=1MHz		0.6	1.0	pF	
Cut-off frequency	f _c	V _{CE} =2V, I _c =2mA, R _L =100Ω	1	6	—	kHz	
Transfer characteristics	Rise time	t _r	V _{CE} =2V, I _c =10mA, R _L =100Ω		60	300	μs
	Fall time	t _f	V _{CE} =2V, I _c =10mA, R _L =100Ω	—	53	250	μs

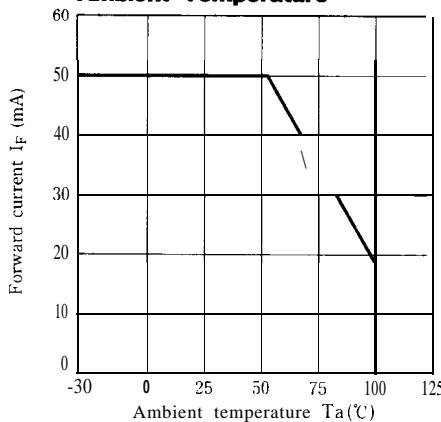
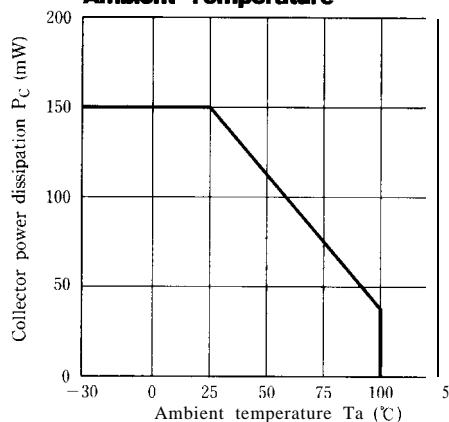
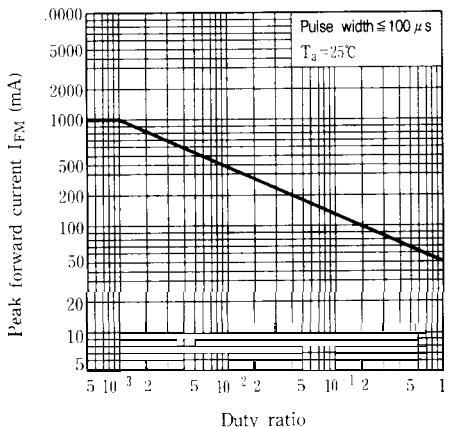
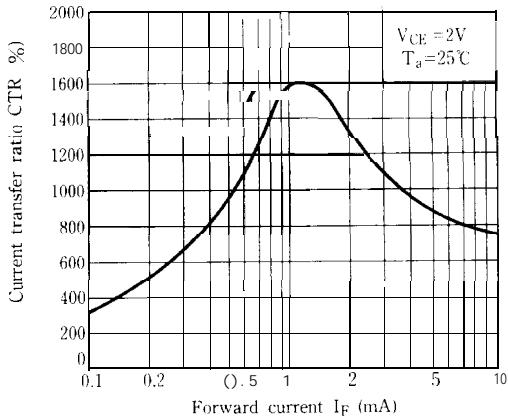
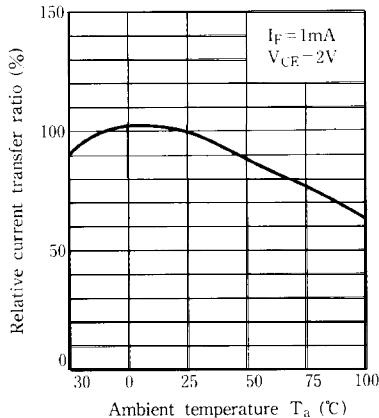
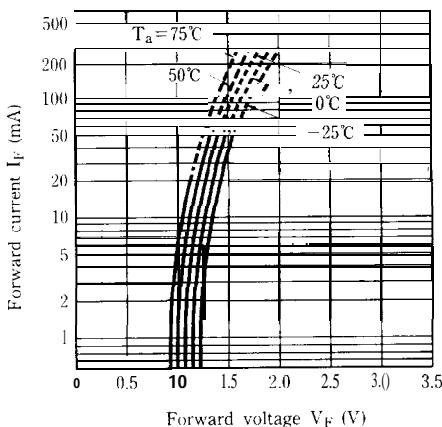
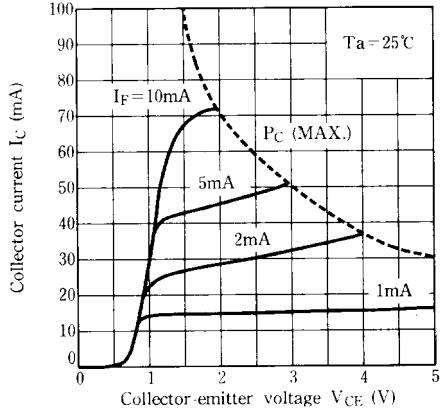
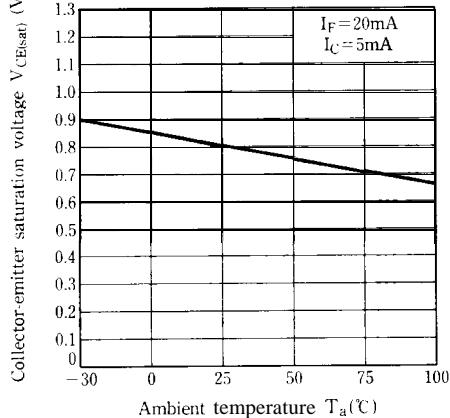
Fig. 1 Forward Current vs. Ambient Temperature**Fig. 2 Collector Power Dissipation vs. Ambient Temperature**

Fig. 3 Peak Forward Current vs. Duty Ratio**Fig. 5 Current Transfer Ratio vs. Forward Current****Fig. 7 Relative Current Transfer Ratio vs. Ambient Temperature****Fig. 4 Forward Current vs. Forward Voltage****Fig. 6 Collector Current vs. Collector-emitter Voltage****Fig. 8 Collector-emitter Saturation Voltage vs. Ambient Temperature**

9 Collector Dark Current vs. Ambient Temperature

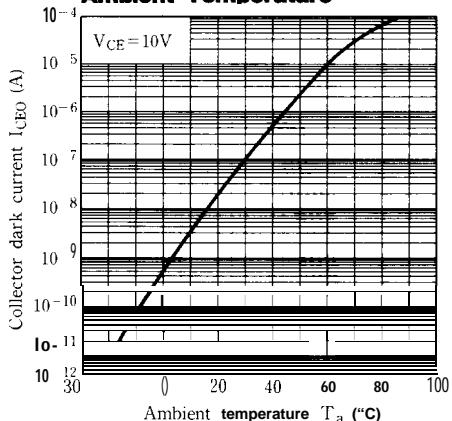


Fig.10 Response Time vs. Load Resistance

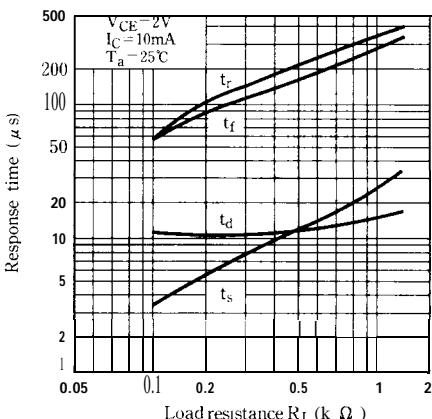
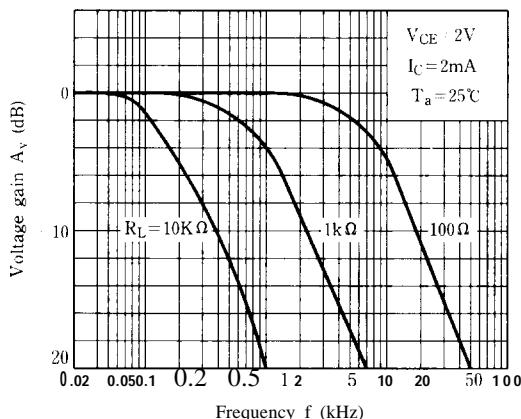


Fig.11 Frequency Response



Test Circuit for Response Time

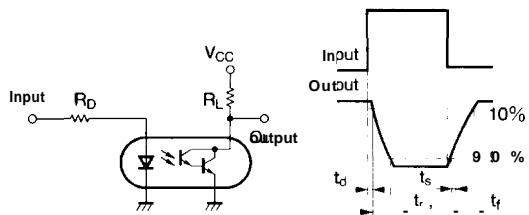
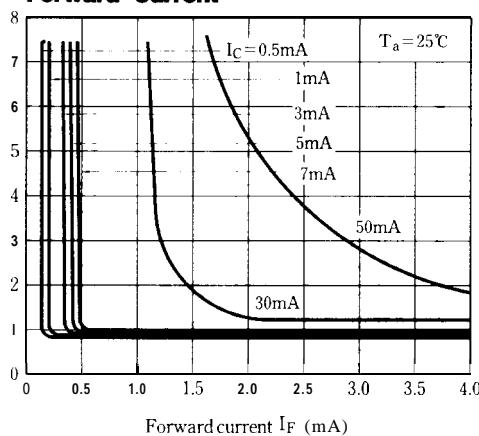
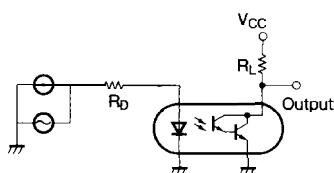


Fig.12 Collector-emitter Saturation Voltage vs. Forward Current



Test Circuit for Frequency Response



- Please refer to the chapter "Precautions for Use" (Page 78 to 93)